

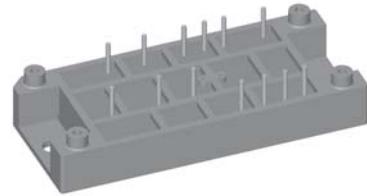
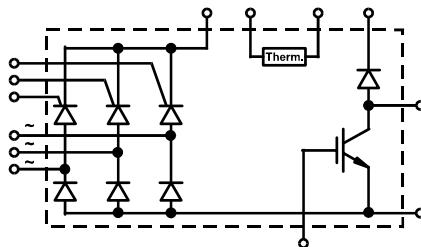
Three Phase Half Controlled Rectifier Bridge with IGBT and Fast Recovery Diode for Braking System

V_{RRM} = 1200/1600 V
I_{dAV} = 120 A

Preliminary data

V _{RRM} V	Type
1200	VVZB 120-12 io2(T)
1600	VVZB 120-16 io2(T)

(T) = NTC optional



Symbol	Conditions	Maximum Ratings		
I_{dAV} I_{FRMS}/I_{TRMS}	$T_{case} = 80^\circ\text{C}$, sinusoidal 120°	120	A	
	$T_{case} = 80^\circ\text{C}$, per leg	77	A	
I_{FSM}/I_{TSM}	$T_{VJ} = 25^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	750	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	670	A	
I^2t	$T_{VJ} = 25^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	2810	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	2240	A	
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50 \text{ Hz}$, $t_p = 200 \mu\text{s}$	repetitive, $I_T = 150 \text{ A}$	150	$\text{A}/\mu\text{s}$
	$V_D = \frac{2}{3} V_{DRM}$ $I_G = 0.45 \text{ A}$, $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	non repetitive, $I_T = I_{d(AV)}/3$	500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$; $V_{DR} = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$; method 1 (linear voltage rise)		1000	$\text{V}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM}$	$t_p = 30 \mu\text{s}$	10	W
	$I_T = I_{d(AV)}/3$	$t_p = 300 \mu\text{s}$	5	W
		$t_p = 10 \text{ ms}$	1	W
P_{GAVM}			0.5	W
V_{CES} V_{GE}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	1200	V	
	Continuous	± 20	V	
I_{C25}	$T_{case} = 25^\circ\text{C}$, DC	140	A	
I_{C80}	$T_{case} = 80^\circ\text{C}$, DC	100	A	
I_{CM}	t_p = Pulse width limited by T_{VJM}	280	A	
P_{tot}	$T_{case} = 80^\circ\text{C}$	570	W	
V_{RRM}		1200	V	
$I_{F(AV)}$ $I_{F(RMS)}$ I_{FRM}	$T_{case} = 80^\circ\text{C}$, rectangular $d = 0.5$	27	A	
	$T_{case} = 80^\circ\text{C}$, rectangular $d = 0.5$	38	A	
	$T_{case} = 80^\circ\text{C}$, $t_p = 10 \mu\text{s}$, $f = 5 \text{ kHz}$	tbd	A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$, $t = 10 \text{ ms}$	200	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$	180	A	
P_{tot}	$T_{case} = 80^\circ\text{C}$	64	W	

Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions.

Symbol	Conditions	Characteristic Values		
		$(T_{VJ} = 25^\circ C$, unless otherwise specified)		
		min.	typ.	max.
I_R, I_D	$V_R = V_{RRM}/V_{DRM}$, $V_R = V_{RRM}/V_{DRM}, T_{VJ} = 150^\circ C$		0.3 mA 5 mA	
V_F, V_T	$I_F = 100 A$,		1.47 V	
V_{TO} r_T	For power-loss calculations only $T_{VJ} = 150^\circ C$		0.85 V 5 mΩ	
V_{GT}	$V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1.5 V 1.6 V	
I_{GT}	$V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		100 mA 200 mA	
V_{GD} I_{GD}	$T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$		0.2 V 10 mA	
I_L	$V_D = 6 V; t_G = 30 \mu s$ $di_G/dt = 0.45 A/\mu s; I_G = 0.45 A$		450 mA	
I_H	$T_{VJ} = T_{VJM}; V_D = 6 V; R_{GK} = \infty$		200 mA	
t_{gd}	$V_D = \frac{1}{2} V_{DRM}$ $di_G/dt = 0.45 A/\mu s; I_G = 0.45 A$		2 μs	
t_q	$T_{VJ} = T_{VJM}; V_R = 100 V; V_D = \frac{2}{3} V_{DRM}; t_p = 200 \mu s$ $dv/dt = 10 V/\mu s; I_T = 120 A; -di/dt = 10 A/\mu s$		150 μs	
Q_S I_{RM}	$\left. \begin{array}{l} T_{VJ} = T_{VJM} \\ -di/dt = 0.64 A/\mu s; I_T/I_F = 50 A \end{array} \right\}$		90 μC 11 A	
R_{thJC} R_{thJH}	per thyristor / diode; sine 120° el. per thyristor / diode; sine 120° el.		1 K/W 1.3 K/W	
$V_{BR(CES)}$ $V_{GE(th)}$	$V_{GS} = 0 V, I_C = 1 mA$ $I_C = 4 mA$	1200 4.5	V 6.5	
I_{GES}	$V_{GE} = \pm 20 V$		500 nA	
I_{CES}	$V_{CE} = V_{CES}$ $V_{CE} = V_{CES}, T_{VJ} = 125^\circ C$		0.2 mA 1 mA	
V_{CESat}	$V_{GE} = 15 V, I_C = 50 A$		2.1 V	
t_{sc} (SCSOA)	$V_{GE} = 15 V, V_{CE} = 900 V, T_{VJ} = 125^\circ C,$ $R_G = 15 \Omega$, non repetitive		10 μs	
$RB SOA$	$V_{GE} = 15 V, V_{CE} = 1200 V, T_{VJ} = 125^\circ C,$ $R_G = 15 \Omega$, Clamped Inductive load, $L = 100 \mu H$		150 A	
C_{ies}	$V_{CE} = 25 V, f = 1 MHz, V_{GE} = 0 V$	5.7	nF	
$t_{d(on)}$ $t_{d(off)}$ E_{on} E_{off}	$\left. \begin{array}{l} V_{CE} = 600 V, I_C = 50 A \\ V_{GE} = 15 V, R_G = 15 \Omega \\ \text{Inductive load; } L = 100 \mu H \\ T_{VJ} = 125^\circ C \end{array} \right\}$	170 680 11 8	ns ns mJ mJ	
R_{thJC} R_{thCH}		0.1	0.22 K/W K/W	

Symbol	Conditions	Characteristic Values		
		$(T_{VJ} = 25^\circ C, \text{unless otherwise specified})$		
		min.	typ.	max.
I_R	$V_R = V_{RRM}, T_{VJ} = 25^\circ C$ $V_R = 0.8 V_{RRM}, T_{VJ} = 150^\circ C$	3	0.75 mA 7 mA	
V_F	$I_F = 30 A, T_{VJ} = 25^\circ C$		2.55 V	
V_{TO} r_T	For power-loss calculations only $T_{VJ} = 150^\circ C$		1.65 V 18.2 mΩ	
I_{RM}	$I_F = 30 A, -di_F/dt = 240 A/\mu s$ $V_R = 100 V$	16	18 A	
t_{rr}	$I_F = 1 A, -di_F/dt = 100 A/\mu s$ $V_R = 30 V$	40	60 ns	
R_{thJC} R_{thJH}			1.1 K/W 1.5 K/W	
Common Specification				
T_{VJ}		-40...+150		°C
T_{VJM}		150		°C
T_{stg}		-40...+125		°C
V_{ISOL}	50/60 Hz $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	3000 V~ 3600 V~	
M_d	Mounting torque (M5) (10-32 unf)		2-2.5 Nm 18-22 lb.in.	
Weight	typ.		80 g	
d_s	Creep distance on surface		12.7 mm	
d_A	Strike distance in air		11 mm	
a	Maximum allowable acceleration		50 m/s ²	
		min.	typ.	max.
R_{25} $B_{25/100}$	Thermistor	4.75	5.0 kΩ 3375	5.25 kΩ K

Dimensions in mm (1 mm = 0.0394")

